

# Vishay General Semiconductor

## **Surface Mount Glass Passivated Junction Rectifier**

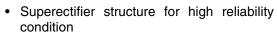


\*Glass-plastic encapsulation is covered by Patent No. 3,996,602, brazed-lead assembly to Patent No. 3,930,306

DO-213AB

# $\begin{tabular}{lllll} \textbf{MAJOR RATINGS AND CHARACTERISTICS} \\ & I_{F(AV)} & 1.0 \text{ A} \\ & V_{RRM} & 50 \text{ V to } 1000 \text{ V} \\ & I_{FSM} & 30 \text{ A} \\ & I_{R} & 10 \text{ } \mu\text{A} \\ & V_{F} & 1.1 \text{ V} \\ & T_{j} \text{ max.} & 175 \text{ °C} \\ \end{tabular}$

### **FEATURES**



- Patented glass-plastic encapsulation technique
- · Ideal for automated placement
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020C, LF max peak of 250 °C
- Solder Dip 260 °C, 40 seconds
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in general purpose rectification of power supplies, inverters, converters and free-wheeling diodes for consumer, automotive and telecommunication.

### **MECHANICAL DATA**

Case: DO-213AB, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D

E3 suffix for commercial grade, HE3 suffix for high

reliability grade (AEC Q101 qualified)

**Polarity:** Two bands indicate cathode end - 1st band denotes device type and 2nd band denotes repetitive peak reverse voltage rating

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)									
PARAMETER									
STANDARD RECOVERY TIME DEVICE: 1ST BAND IS WHITE	SYMBOL	1N6478	1N6479	1N6480	1N6481	1N6482	1N6483	1N6484	UNIT
Polarity color bands (2nd Band)		Gray	Red	Orange	Yellow	Green	Blue	Violet	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	I <sub>F(AV)</sub>	l <sub>F(AV)</sub> 1.0					Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	I <sub>FSM</sub> 30					Α		
Maximum full load reverse current, full cycle average at $T_A = 75\ ^{\circ}\text{C}$	I <sub>R(AV)</sub> 100					μΑ			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	T <sub>STG</sub> - 65 to + 175					°C		

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)											
PARAMETER	TEST C	ONDITIONS	SYMBOL	1N6478	1N6479	1N6480	1N6481	1N6482	1N6483	1N6484	UNIT
Maximum instantaneous forward voltage	at 1.0 A	T <sub>A</sub> = 25 °C T <sub>A</sub> = 75 °C	V <sub>F</sub>				1.1 1.0				>
Maximum DC reverse current at rated DC blocking voltage		T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>				10 200				μΑ
Typical junction capacitance	at 4.0 V, 1	MHz	CJ				8.0				pF

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	1N6478 1N6479 1N6480 1N6481			1N6482	1N6483	1N6484	UNIT
Maximum thermal resistance (1,2)	$R_{ hetaJA} \ R_{ hetaJT}$	50 20				°C/W		

### Note:

- (1) Thermal resistance from junction to ambient, 0.24 x 0.24" (6.0 x 6.0 mm) copper pads to each terminal
- (2) Thermal resistance from junction to terminal, 0.24 x 0.24" (6.0 x 6.0 mm) copper pads to each terminal

ORDERING INFORMATION								
PREFERRED P/N	UNIT WEIGHT (g)	REFERRED PACKAGE	BASE QUANTITY	DELIVERY MODE				
1N6482-E3/96	0.114	96	1500	7" Diameter Plastic Tape & Reel				
1N6482-E3/97	0.114	97	5000	13" Diameter Plastic Tape & Reel				

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

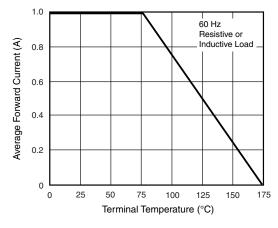


Figure 1. Forward Current Derating Curve

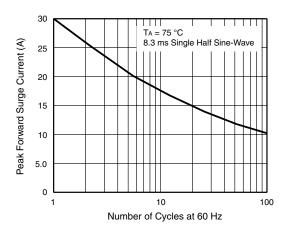


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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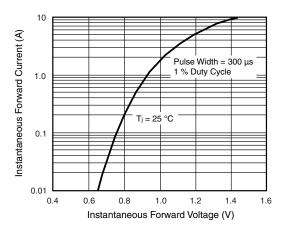


Figure 3. Typical Instantaneous Forward Characteristics

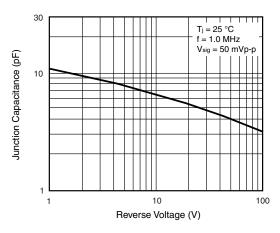


Figure 5. Typical Junction Capacitance

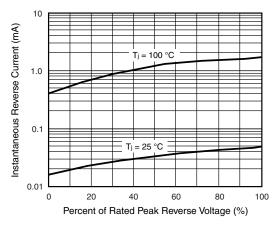


Figure 4. Typical Reverse Characteristics

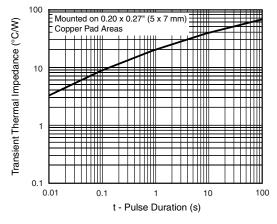
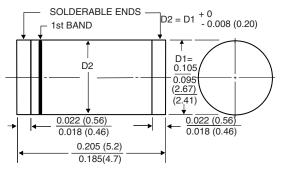


Figure 6. Typical Transient Thermal Impedance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### DO-213AB



1st band denotes type and positive end (cathode)

# **Legal Disclaimer Notice**



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